

**PRECISION, SINGLE SUPPLY, RAIL-TO-RAIL OUTPUT  
DUAL OPERATIONAL AMPLIFIER**

**FEATURES**

- Supply Voltage 4V to 35V ( $\pm 2V$  to  $\pm 17.5V$ )
- Input Offset Voltage 450 $\mu V$  max.
- Input Offset Voltage Drift 2 $\mu V/^{\circ}C$  typ.
- Rail-to-Rail Output
- Ground Sensing
- Input Voltage Protection  $V_{IN}=V^{+}+20V$  ( $@V^{+}\leq 16V$ )
- Integrated EMI Filter
- Operating Temperature Range -40 to 125 $^{\circ}C$
- Slew Rate 0.15V/ $\mu s$
- Gain Bandwidth Product 300kHz
- Supply Current (All Amplifiers) 2mA max.
- Package DMP8

**DESCRIPTION**

The NJM8207 is a high-precision, rail-to-rail, dual operational amplifier featuring low offset voltage, low temperature drift and low input bias current. It is suitable for high-precision amplification circuit for measurement and sensor amplifier.

The NJM8207 operates from a single supply 4V to 35V, or a wide voltage from  $\pm 2V$  to  $\pm 17.5V$  for dual supply. Rail-to-rail output swing significantly increases voltage range and enhances the Op-Amp general purpose. Since the common-mode input voltage range includes  $V^{-}$ , ground sensing is possible when it operates with a single supply.

The NJM8207 has high RF noise immunity and reduces malfunction due to high frequency influences of mobile phones and others. This is available in an 8-pin DMP package.

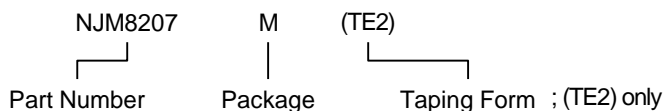
**APPLICATIONS**

- Load Cell and Bridge Transducer Amplifiers
- Current Sensor Amplifiers
- High Resolution Data Acquisition
- Power Line Monitoring

**PIN CONFIGURATIONS**

PRODUCT NAME	NJM8207M
Package	DMP8
Pin Functions	

## ■ PRODUCT NAME INFORMATION



## ■ ORDER INFORMATION

PRODUCT NAME	PACKAGE	RoHS	HALOGEN-FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	Quantity (pcs/reel)
NJM8207M	DMP8	Yes	—	Sn2Bi	8207	95	2000

## ■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V^+ - V^-$	36 ( $\pm 18$ )	V
Differential Input Voltage <sup>(1)</sup>	$V_{ID}$	$\pm 36$	V
Input Voltage <sup>(2)</sup>	$V_{IN}$	$V - 0.3$ to $V + 36$	V
Power Dissipation <sup>(3)</sup>	$P_D$	2-Layer / 4-Layer <sup>(4)</sup>	mW
DMP8		530 / 710	
Storage Temperature Range	$T_{stg}$	-50 to 150	°C
Maximum Junction Temperature	$T_{jmax}$	150	°C

## ■ THERMAL CHARACTERISTICS

PACKAGE	SYMBOL	VALUE	UNIT
Junction-to-Ambient Thermal Resistance	$\theta_{ja}$	2-Layer / 4-Layer <sup>(4)</sup>	°C/W
DMP8		235 / 175	
Junction-to-Top of Package Characterization Parameter	$\Psi_{jt}$	2-Layer / 4-Layer <sup>(4)</sup>	°C/W
DMP8		47 / 40	

(1) Differential voltage is the voltage difference between +INPUT and -INPUT.

(2) Input voltage is the voltage should be allowed to apply to the input terminal independent of the magnitude of  $V^+$ .

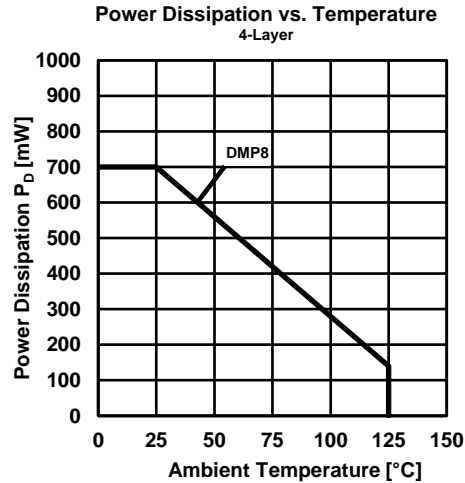
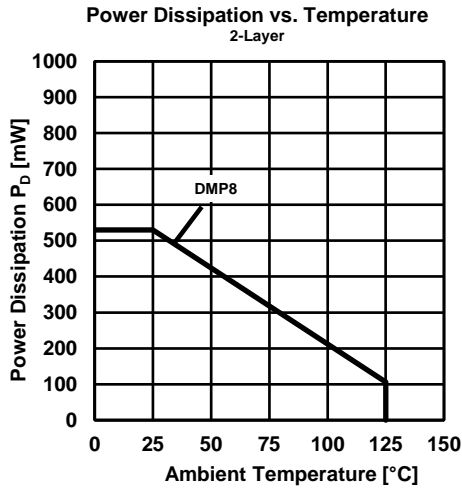
The normal operation will establish when any input is within the "Common-Mode Input Voltage Range" of electrical characteristics.

(3) Power dissipation is the power that can be consumed by the IC at  $T_a = 25^\circ\text{C}$ , and is the typical measured value based on JEDEC condition.

(4) 2-Layer: Mounted on glass epoxy board. (76.2x114.3x1.6 mm: based on EIA/JDEC standard, 2-layer FR-4)

4-Layer: Mounted on glass epoxy board. (76.2x114.3x1.6 mm: based on EIA/JDEC standard, 4-layer FR-4), internal Cu area: 74.2 x 74.2 mm

■ **POWER DISSIPATION vs. AMBIENT TEMPERATURE**



■ **RECOMMENDED OPERATING CONDITIONS**

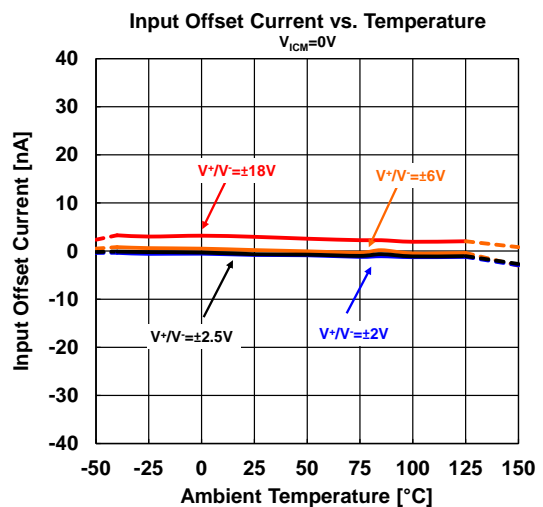
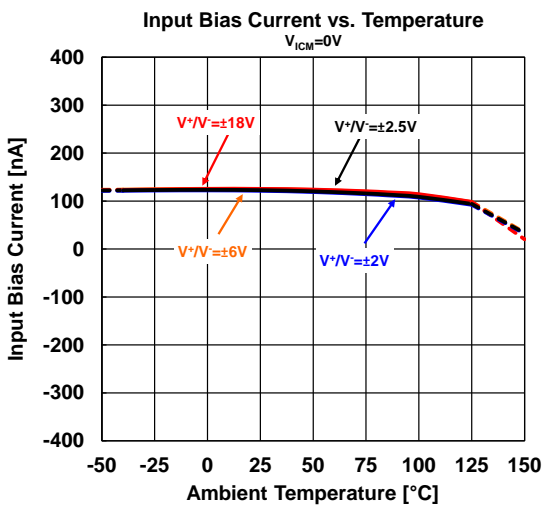
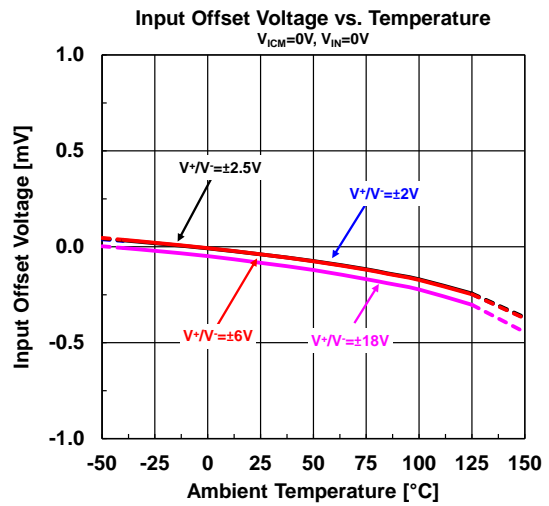
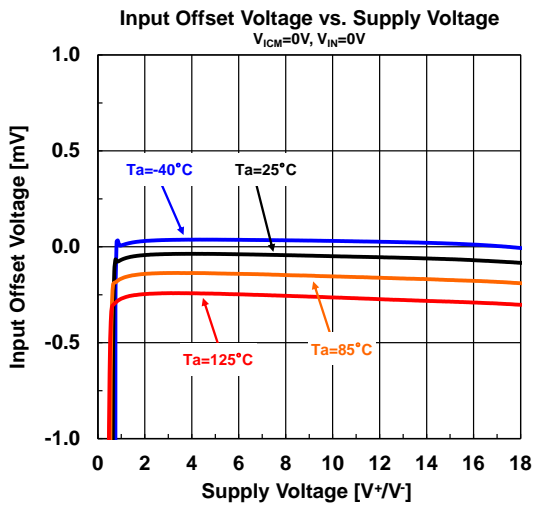
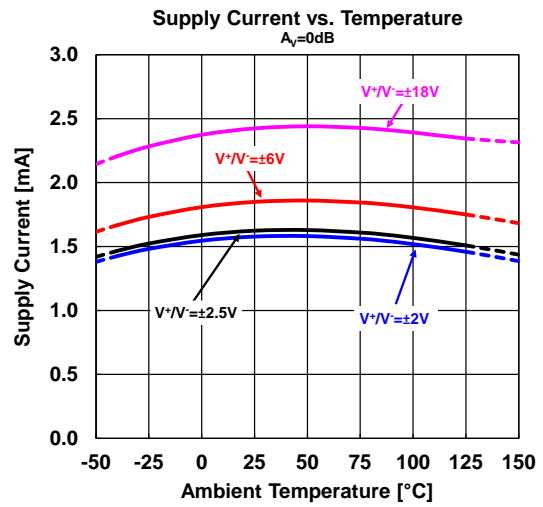
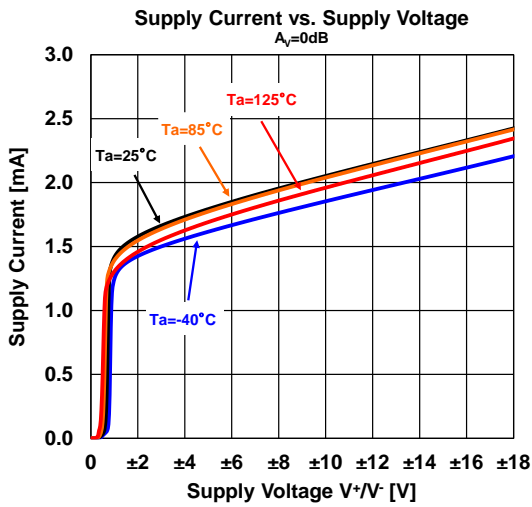
PARAMETER	SYMBOL	CONDITIONS	VALUE	UNIT
Supply Voltage	V <sup>+</sup> - V <sup>-</sup>	T <sub>a</sub> =25°C	4 to 35 (±2 to ±17.5)	V
Operating Temperature Range	T <sub>opr</sub>		-40 to 125	°C

■ **ELECTRICAL CHARACTERISTICS (V<sup>+</sup>=5V, V<sup>-</sup>=0V, T<sub>a</sub>=25°C, unless otherwise noted.)**

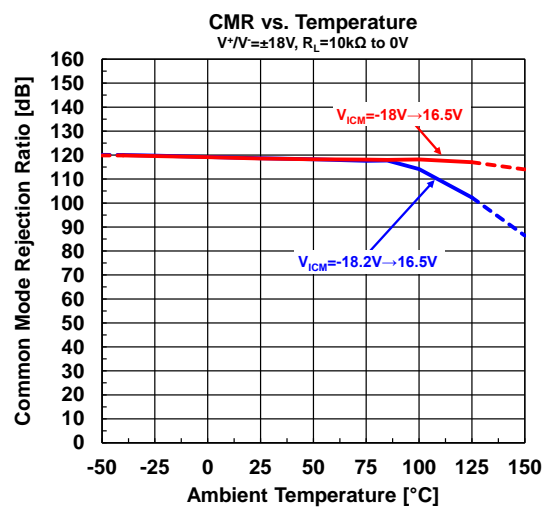
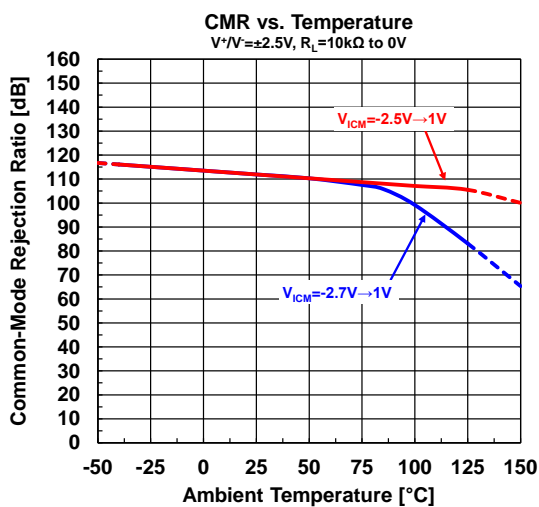
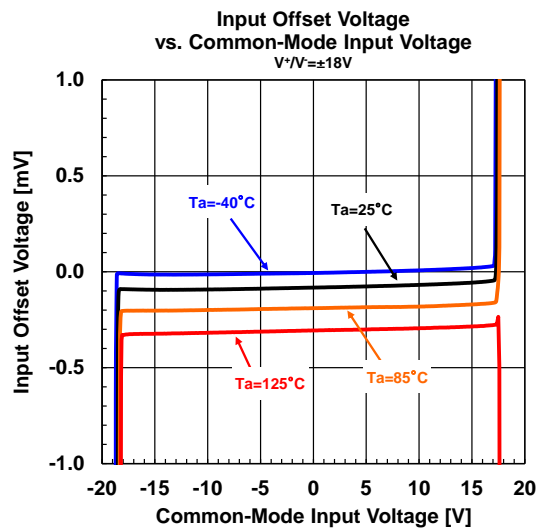
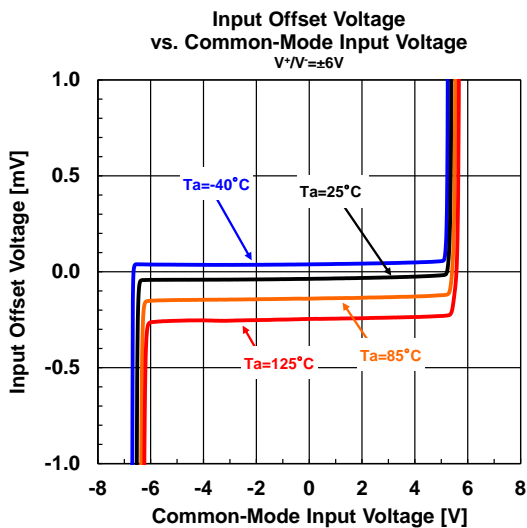
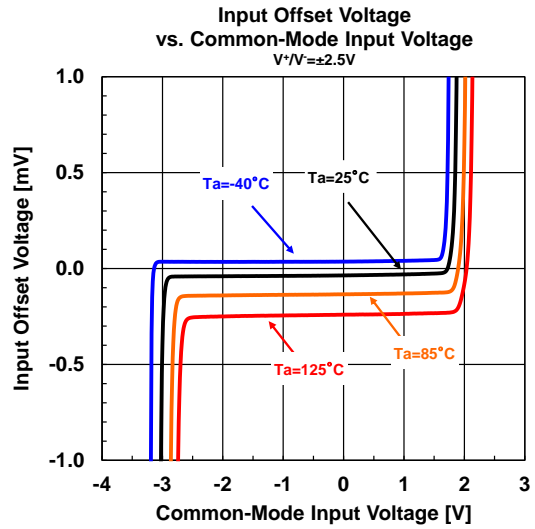
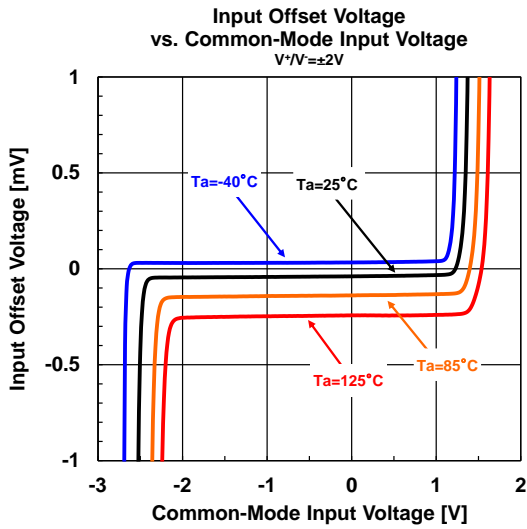
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>INPUT CHARACTERISTICS</b>						
Input Offset Voltage	V <sub>IO</sub>	R <sub>S</sub> =50kΩ, R <sub>F</sub> =50kΩ	-	200	450	μV
Input Bias Current	I <sub>B</sub>		-	120	500	nA
Input Offset Current	I <sub>IO</sub>		-	5	20	nA
Input Offset Voltage Drift	ΔV <sub>IO</sub> /ΔT	T <sub>a</sub> =-40°C to 125°C	-	2	-	μV/°C
Open-Loop Voltage Gain	A <sub>V</sub>	R <sub>L</sub> =10kΩ to 2.5V, V <sub>O</sub> =2.5V±2V	70	90	-	dB
Common-Mode Rejection Ratio	CMR	V <sub>COM</sub> =0V to 3.5V	80	110	-	dB
Common-Mode Input Voltage Range	V <sub>ICM</sub>	CMR≥80dB	0	-	3.5	V
<b>OUTPUT CHARACTERISTICS</b>						
Maximum Output Voltage1	V <sub>OH1</sub>	R <sub>L</sub> ≥2kΩ to 2.5V	4.85	4.95	-	V
	V <sub>OL1</sub>	R <sub>L</sub> ≥2kΩ to 2.5V	-	0.05	0.15	V
Maximum Output Voltage2	V <sub>OH2</sub>	R <sub>L</sub> ≥2kΩ to GND	4.85	4.95	-	V
	V <sub>OL2</sub>	R <sub>L</sub> ≥2kΩ to GND	-	0.05	0.15	V
Output Current	I <sub>OUT</sub>	V <sub>OH</sub> ≥4.75V, V <sub>OL</sub> ≤0.25V	2	10	-	mA
<b>POWER SUPPLY</b>						
Supply Current (All Amplifiers)	I <sub>SUPPLY</sub>	No Signal	-	1.4	2	mA
Supply Voltage Rejection Ratio	SVR	V <sup>+</sup> /V <sup>-</sup> = ±2V to ±8V	80	110	-	dB
<b>AC CHARACTERISTICS</b>						
Slew Rate	SR	A <sub>V</sub> =1, V <sub>IN</sub> =2V <sub>PP</sub> , R <sub>L</sub> =10kΩ to 2.5V, C <sub>L</sub> =10pF, <sup>(5)</sup>	-	0.15	-	V/μs
Unity Gain Frequency	f <sub>T</sub>	G <sub>V</sub> =40dB, R <sub>L</sub> =10kΩ, C <sub>L</sub> =15pF	-	300	-	kHz
Phase Margin	Φ <sub>M</sub>	G <sub>V</sub> =40dB, R <sub>L</sub> =10kΩ, C <sub>L</sub> =15pF	-	50	-	deg
Gain Margin	G <sub>M</sub>	G <sub>V</sub> =40dB, R <sub>L</sub> =10kΩ, C <sub>L</sub> =15pF	-	12	-	dB
Channel Separation	CS	f=1kHz, G <sub>V</sub> =40dB, R <sub>L</sub> =10kΩ to 2.5V	-	120	-	dB

(5) Slew rate is defined by the lower value of the rise or fall.

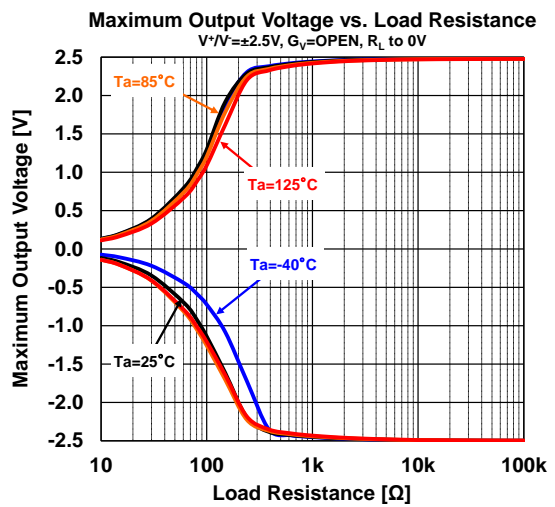
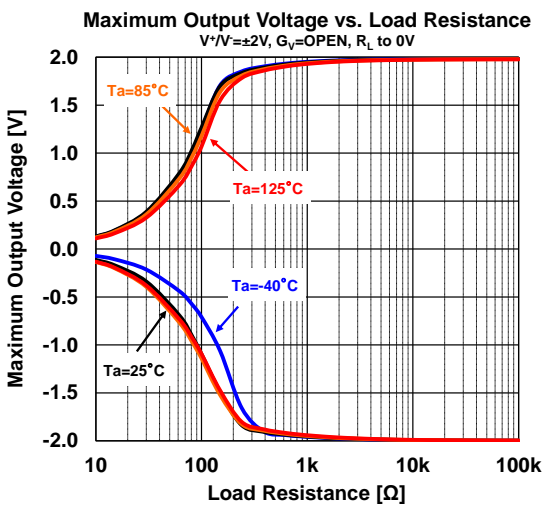
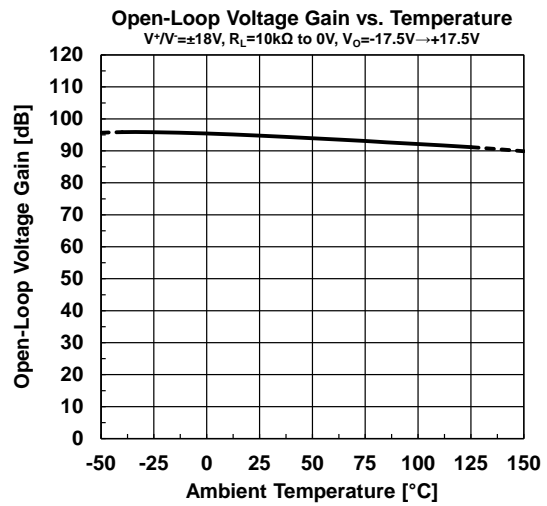
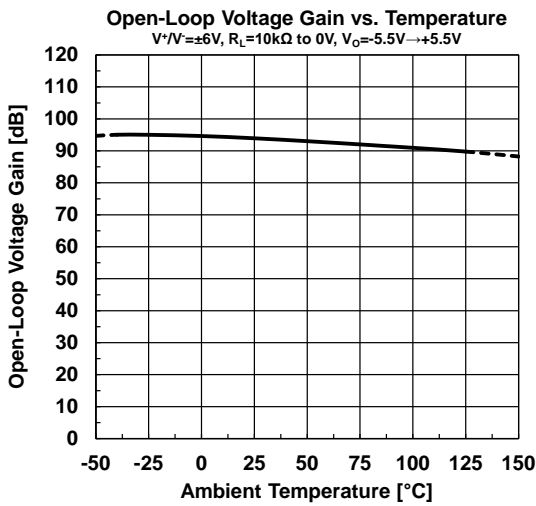
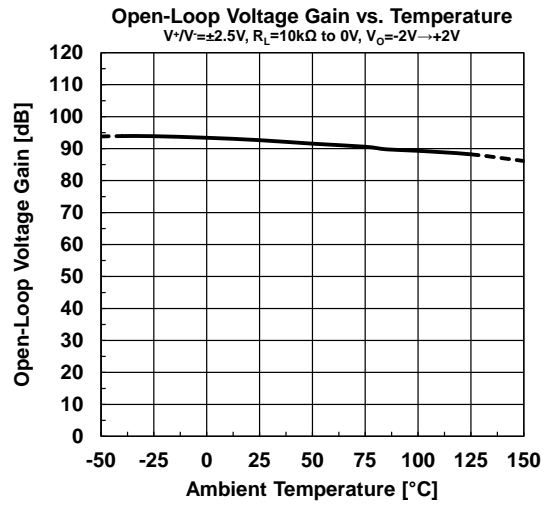
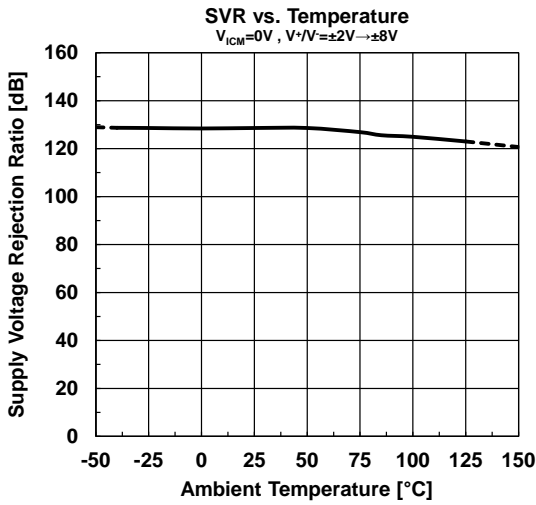
■ TYPICAL CHARACTERISTICS



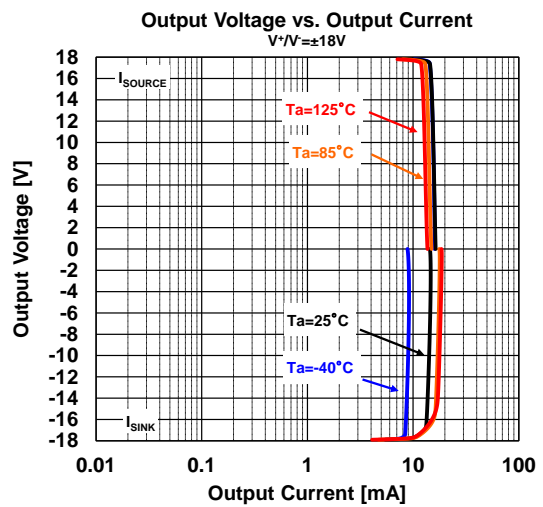
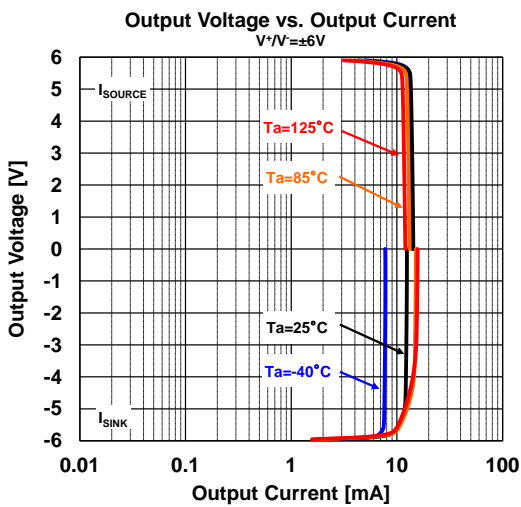
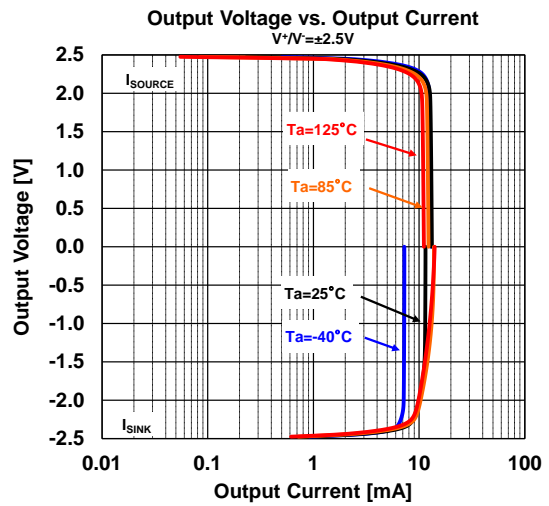
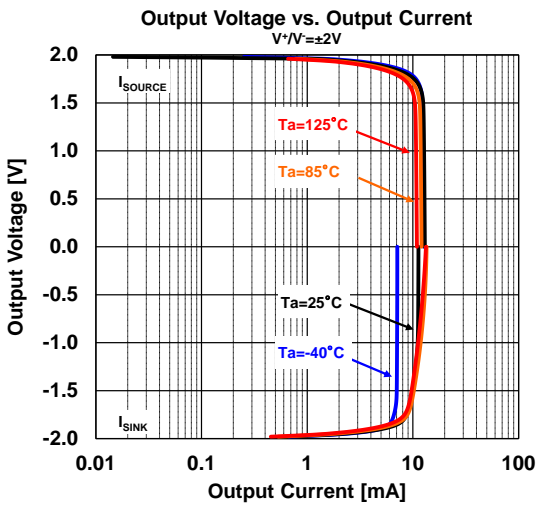
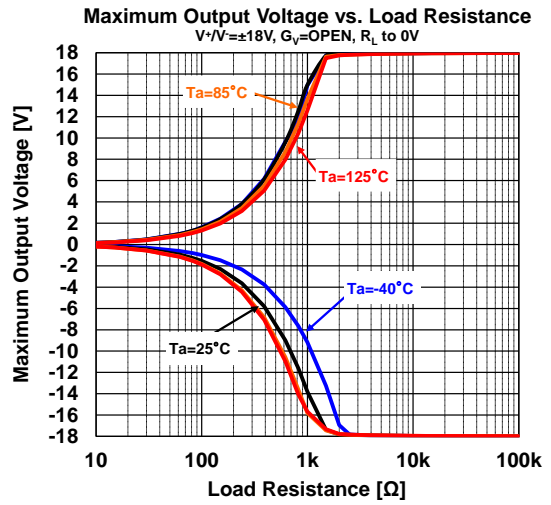
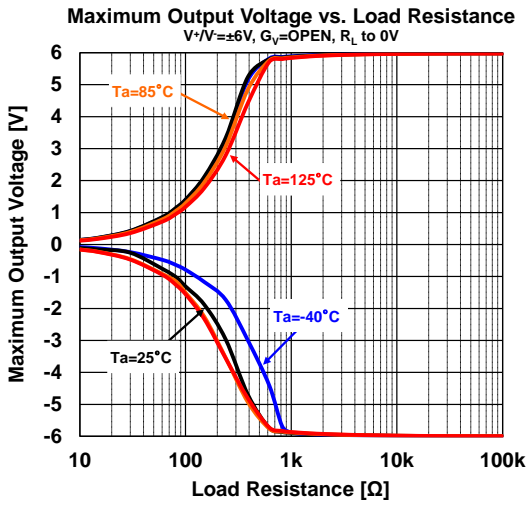
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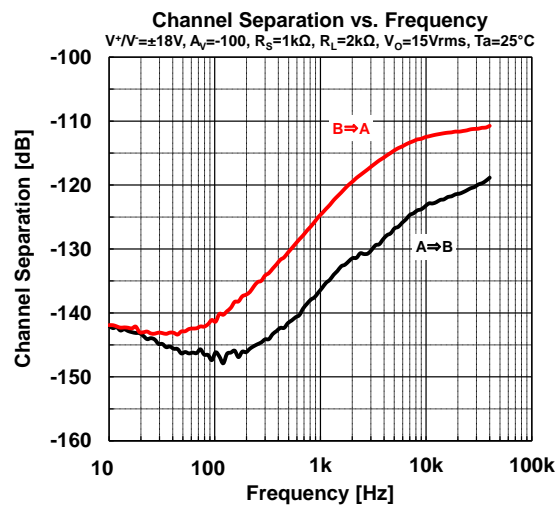
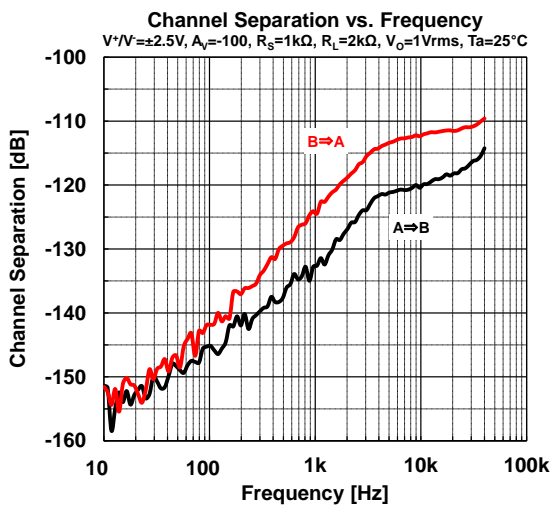
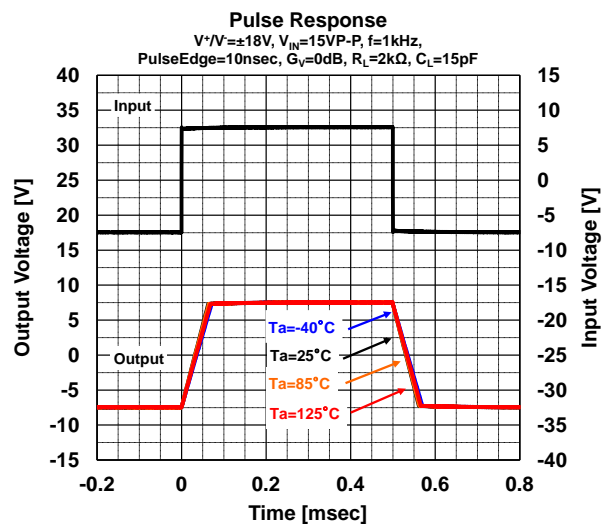
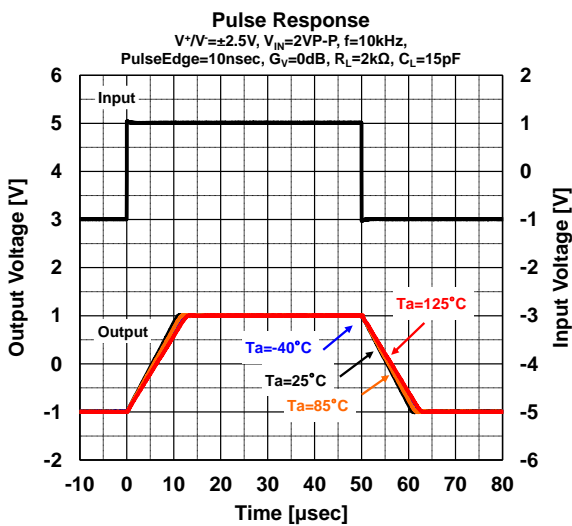
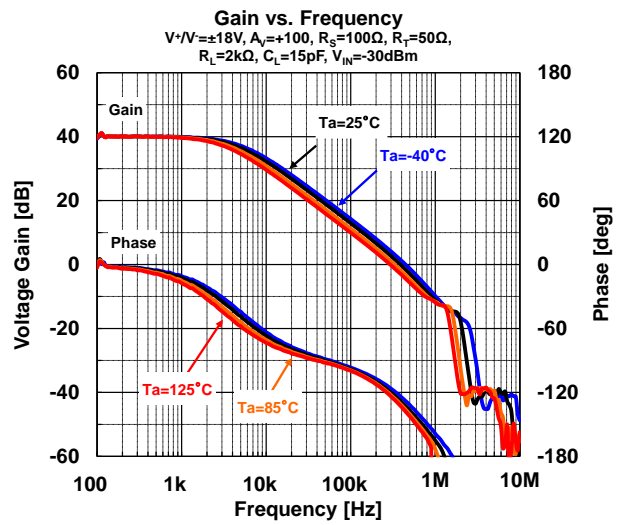
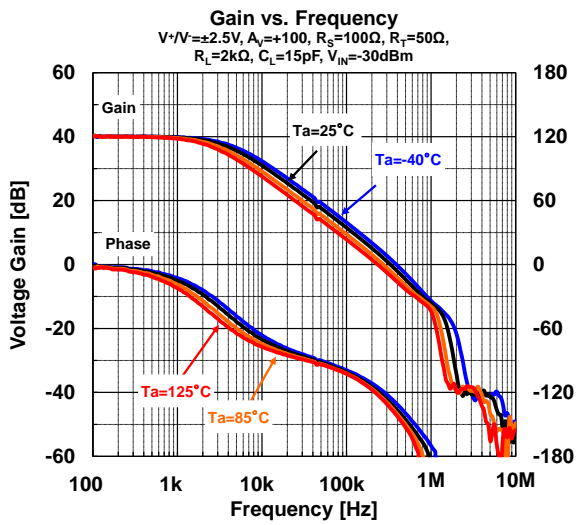
■ TYPICAL CHARACTERISTICS



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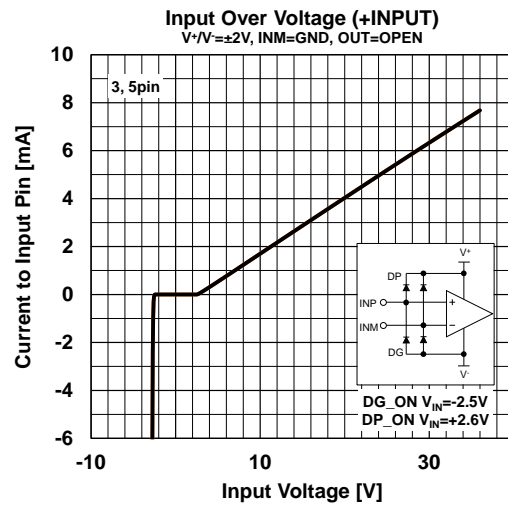
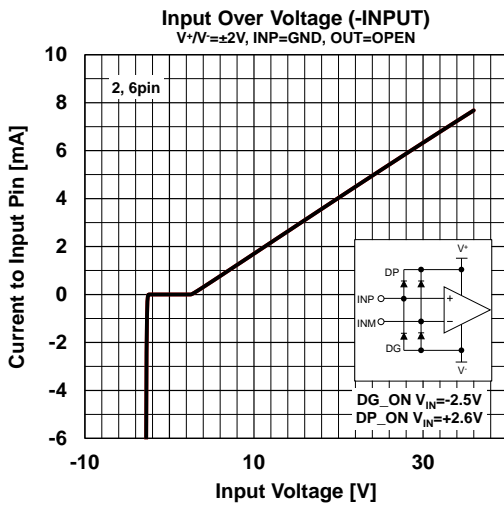


■ TYPICAL CHARACTERISTICS



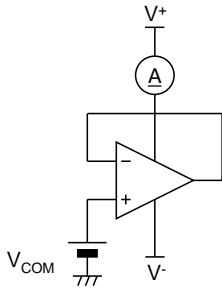


■ TYPICAL CHARACTERISTICS



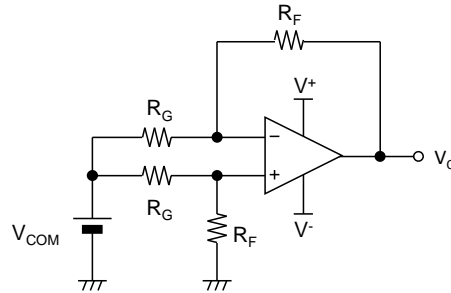
■ TEST CIRCUITS

● I<sub>SUPPLY</sub>



● V<sub>IO</sub>, CMR, SVR

R<sub>G</sub>=50Ω, R<sub>F</sub>=50kΩ



$$V_{IO} = \frac{R_G}{(R_G + R_F)} \times (V_O - V_{com})$$

$$CMR = 20 \log \frac{\Delta V_{com} \left(1 + \frac{R_F}{R_G}\right)}{\Delta V_O}$$

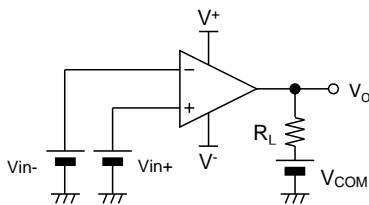
$$SVR = 20 \log \frac{\Delta V_S \left(1 + \frac{R_F}{R_G}\right)}{\Delta V_O}$$

$V_S = V^+ - V^-$

● V<sub>OH</sub>, V<sub>OL</sub>

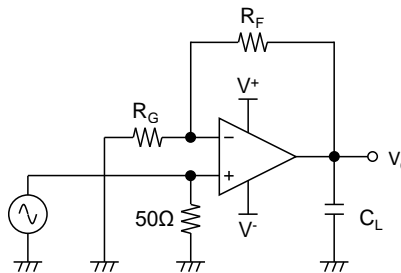
V<sub>OH</sub>: V<sub>in+</sub> = 1V, V<sub>in-</sub> = 0V, V<sub>COM</sub> = V<sup>+</sup>/2, V<sup>-</sup>

V<sub>OL</sub>: V<sub>in+</sub> = 0V, V<sub>in-</sub> = 1V, V<sub>COM</sub> = V<sup>+</sup>/2, V<sup>-</sup>

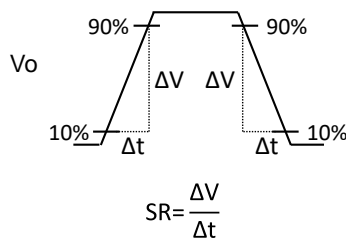
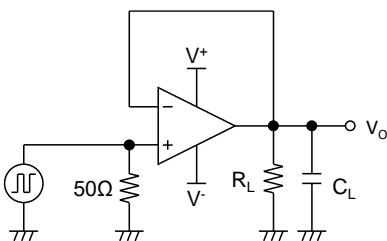


● GBW

R<sub>G</sub>=100Ω, R<sub>F</sub>=10kΩ



● SR



**■ APPLICATION NOTE**
**Single and Dual Supply Voltage Operation**

The NJM8207 works with both single supply and dual supply when the voltage supplied is between  $V^+$  and  $V^-$ . These amplifiers operate from single 4 to 35V supply and dual  $\pm 2V$  to  $\pm 17.5V$  supply.

**Common-Mode Input Voltage Range**

When the supply voltage does not meet the condition of electrical characteristics, the range of common-mode input voltage is as follows:

$$V_{ICM} (\text{typ.}) = V^- \text{ to } V^+ - 1.5V \text{ (Ta = 25°C)}$$

Difference of  $V_{ICM}$  when Temperature change, refer to typical characteristic graph.

During designing, consider variations in characteristics for use with allowance.

**Maximum Output Voltage Range**

When the supply voltage does not meet the condition of electrical characteristics, the range of the typ. value of the maximum output voltage is as follows:

$$V_{OM} (\text{typ.}) = V^- + 0.15V \text{ to } V^+ - 0.15V$$

( $R_L = 2k\Omega$  to GND,  $T_a = 25^\circ\text{C}$ )

During designing, consider variations in characteristics and temperature characteristics for use with allowance. In addition, also note that the output voltage range becomes narrow as shown in typical characteristics graph when an output current increases.

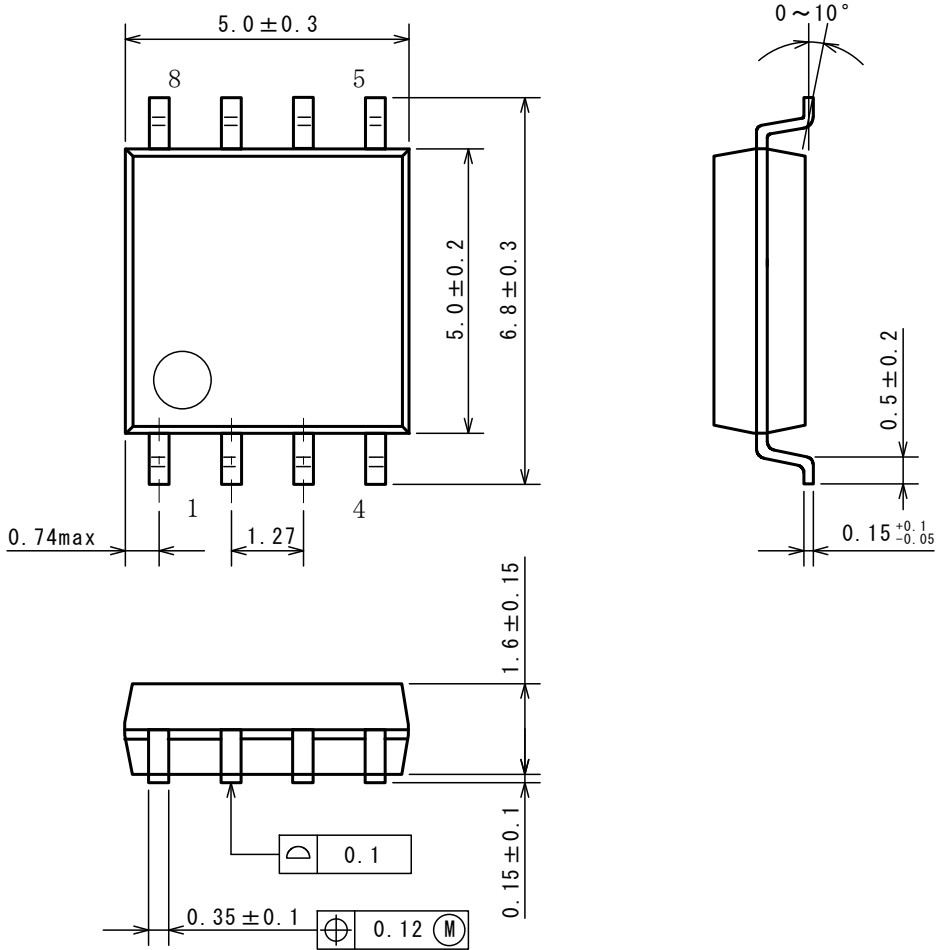
# Nisshinbo Micro Devices Inc.

DMP8

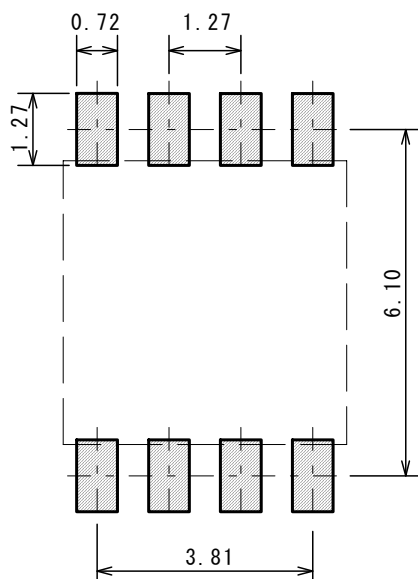
PI-DMP8-E-C

## ■ PACKAGE DIMENSIONS

UNIT: mm



## ■ EXAMPLE OF SOLDER PADS DIMENSIONS



# Nisshinbo Micro Devices Inc.

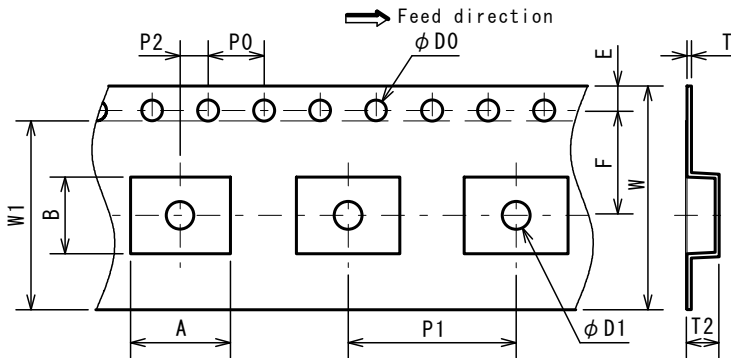
DMP8

PI-DMP8-E-C

■ PACKING SPEC

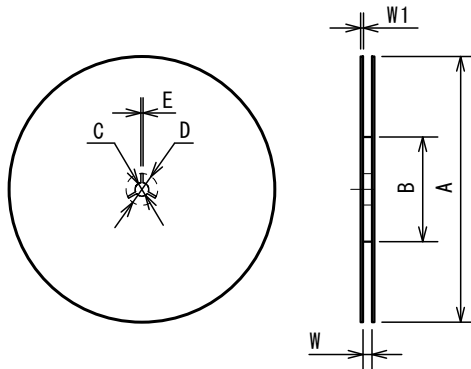
UNIT: mm

TAPING DIMENSIONS



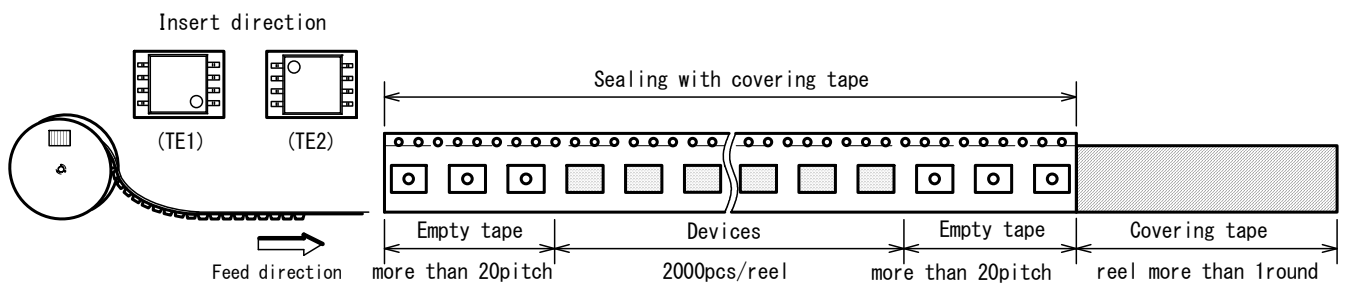
SYMBOL	DIMENSION	REMARKS
A	7.1	BOTTOM DIMENSION
B	5.4	BOTTOM DIMENSION
D0	1.55±0.05	
D1	2.05±0.1	
E	1.75±0.1	
F	7.5±0.1	
P0	4.0±0.1	
P1	12.0±0.1	
P2	2.0±0.1	
T	0.3±0.05	
T2	2.3	
W	16.0±0.3	
W1	13.5	THICKNESS 0.1max

REEL DIMENSIONS

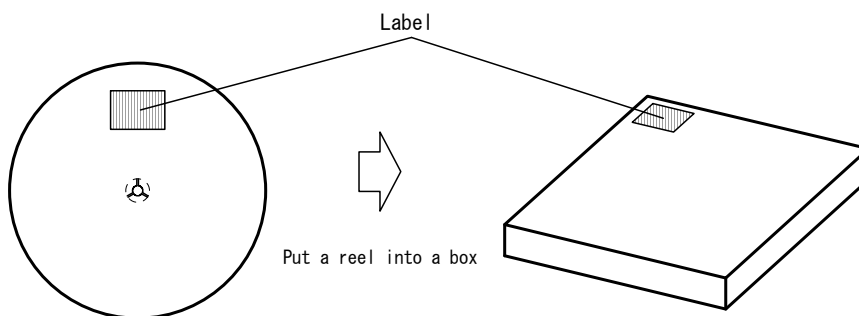


SYMBOL	DIMENSION
A	φ 330±2
B	φ 80±1
C	φ 13±0.2
D	φ 21±0.8
E	2±0.5
W	17.5±0.5
W1	2±0.2

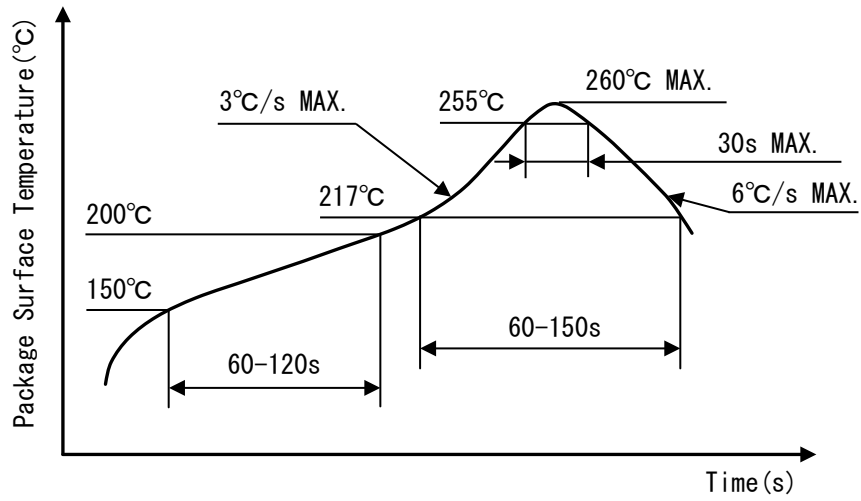
TAPING STATE



PACKING STATE



■ HEAT-RESISTANCE PROFILES



Reflow profile

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  - Equipment Used in the Deep Sea
  - Power Generator Control Equipment (nuclear, steam, hydraulic, etc.)
  - Life Maintenance Medical Equipment
  - Fire Alarms / Intruder Detectors
  - Vehicle Control Equipment (automotive, airplane, railroad, ship, etc.)
  - Various Safety Devices
  - Traffic control system
  - Combustion equipment

In case your company desires to use this product for any applications other than general electronic equipment mentioned above, make sure to contact our company in advance. Note that the important requirements mentioned in this section are not applicable to cases where operation requirements such as application conditions are confirmed by our company in writing after consultation with your company.

6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
8. **Quality Warranty**
  - 8-1. **Quality Warranty Period**

In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.
  - 8-2. **Quality Warranty Remedies**

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
  - 8-3. **Remedies after Quality Warranty Period**

With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
9. Anti-radiation design is not implemented in the products described in this document.
10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



**Nisshinbo Micro Devices Inc.**

**Official website**

<https://www.nisshinbo-microdevices.co.jp/en/>

**Purchase information**

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